

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number:	SS9013HTA
Manufacturer:	onsemi
Package:	TO-226-3, TO-92-3 (TO-226AA) Formed Leads
Availability:	Please confirm with sales

Product Page:

<https://antrexco.com/product/details/onsemi/ss9013hta.html>

Request a Quote:

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Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

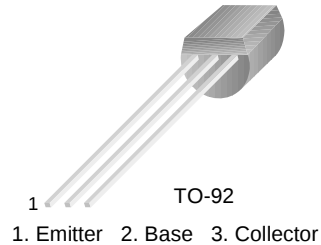
The original manufacturer datasheet follows from the next page.

SS9013

SS9013

1W Output Amplifier of Potable Radios in Class B Push-pull Operation.

- High total power dissipation. ($P_T=625\text{mW}$)
- High Collector Current. ($I_C=500\text{mA}$)
- Complementary to SS9012
- Excellent h_{FE} linearity.



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	40	V
V_{CEO}	Collector-Emitter Voltage	20	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	500	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu\text{A}$, $I_E=0$	40			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=1\text{mA}$, $I_B=0$	20			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=100\mu\text{A}$, $I_C=0$	5			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=25\text{V}$, $I_E=0$			100	nA
I_{EBO}	Emitter Cut-off Current	$V_{EB}=3\text{V}$, $I_C=0$			100	nA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE}=1\text{V}$, $I_C=50\text{mA}$ $V_{CE}=1\text{V}$, $I_C=500\text{mA}$	64 40	120 120	202	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=500\text{mA}$, $I_B=50\text{mA}$		0.16	0.6	V
$V_{BE}(\text{sat})$	Base-Emitter Saturation Voltage	$I_C=500\text{mA}$, $I_B=50\text{mA}$		0.91	1.2	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE}=1\text{V}$, $I_C=10\text{mA}$	0.6	0.67	0.7	V

h_{FE} Classification

Classification	D	E	F	G	H
h_{FE1}	64 ~ 91	78 ~ 112	96 ~ 135	112 ~ 166	144 ~ 202

Typical Characteristics

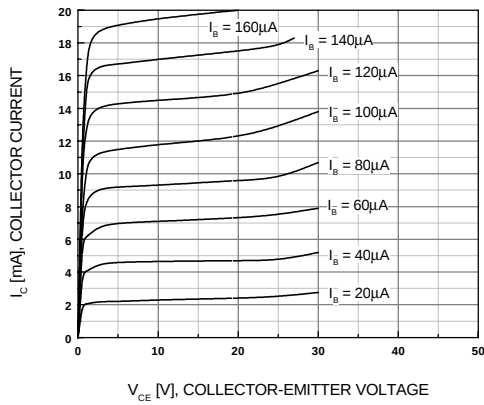


Figure 1. Static Characteristic

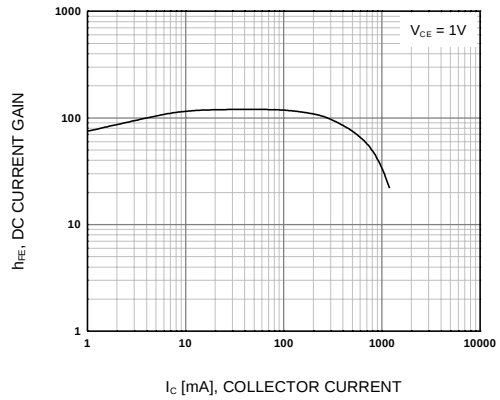


Figure 2. DC current Gain

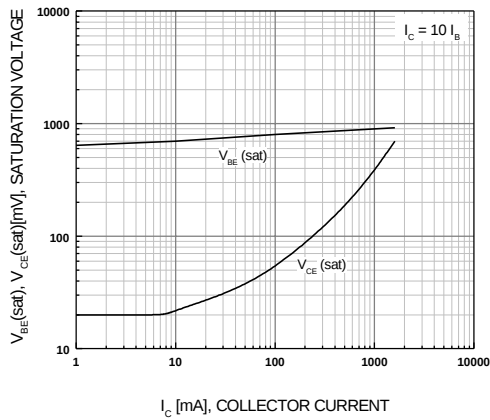


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

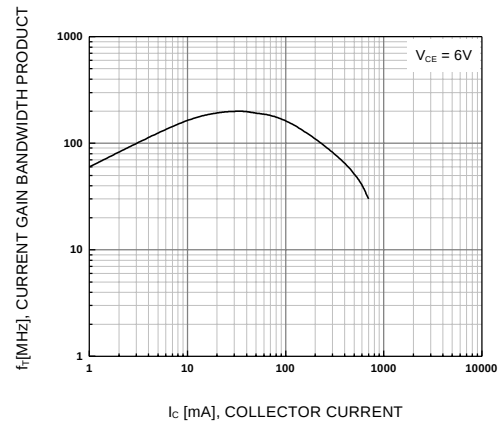
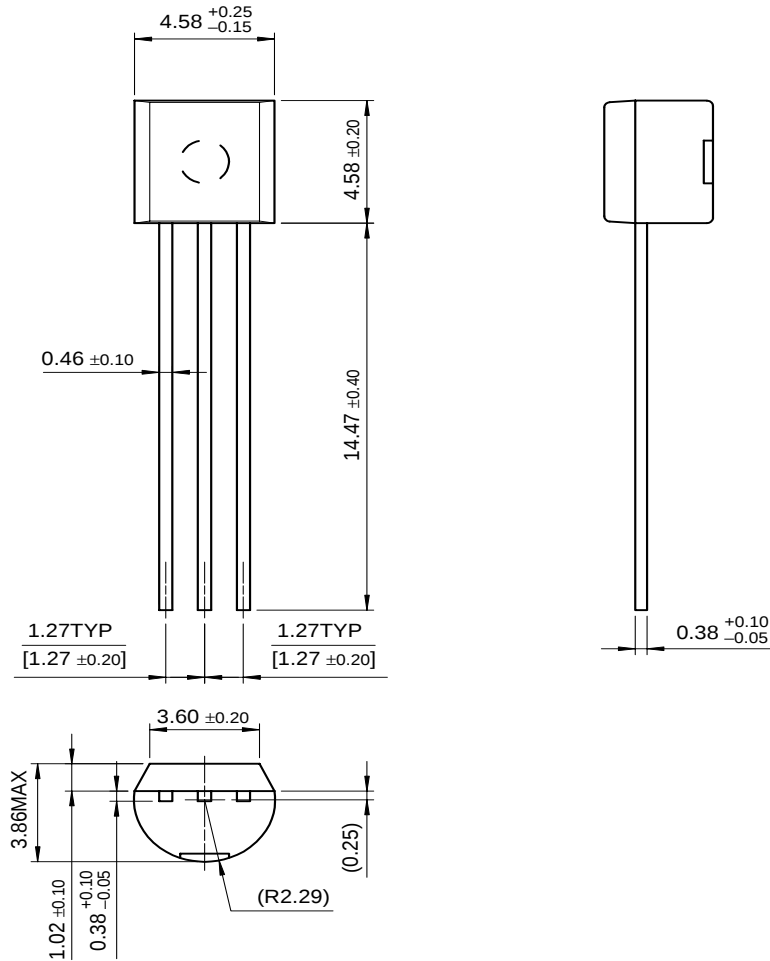


Figure 4. Current Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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